# MOS FET

# Small switching (100V, 5A) 25K2504

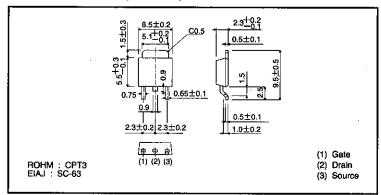
## Features

- 1) Low on-resistance.
- 2) High-speed switching.
- 3) Wide SOA (safe operating area).
- 4) Low-voltage drive (4V).
- 5) Easily designed drive circuits.
- 6) Easy to use in parallel.

#### Structure

Silicon N-channel MOSFET transistor

# External dimensions (Units: mm)



# ◆Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		Voss	100	٧
Gate-source voltage	oltage		±20	٧
Di	Continuous	lo	5	Α
Drain current	Pulsed	lop*	20	Α
Drain reverse correct	Continuous	ious Ion 5	5	Α
Drain reverse current	Pulsed	lose*	20	A
Total power dissipation	n(Tc=25℃)	) P <sub>D</sub> 20		W
Channel temperature		Tch	150	Ç
Storage temperature		Tstg	-55~150	೦

<sup>\*</sup> Pw≤10 μs, Duty cycle≤1%

# Packaging specifications

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	Package	Taping
Туре	Code	TL
	Basic ordering unit (pieces)	2500
2SK2504		0

Transistors 2SK2504

# ●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate leakage current	lgss		_	±100	nA	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V(BR)DSS	100	_	_	٧	lo=1mA, Vgs=0V
Drain cutoff current	loss	_	_	10	μΑ	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V
Gate threshold voltage	VGS(th)	1	_	2.5	٧	Vos=10V, lo=1mA
Drain-source on-state resistance	<b>D</b>		0.18	0.22	Ω	In=2.5A, Vgs=10V
	ADS(on)		0.25	0.28		I <sub>D</sub> =2.5A, V <sub>G</sub> s=4V
Forward propagation admittance	Yts  *	4	_	_	S	V <sub>DS</sub> =10V, I <sub>D</sub> =2.5A
Input capacitance	Ciss		520	_	рF	V <sub>DS</sub> =10V
Output capacitance	Coss	_	175	-	рF	V <sub>GS</sub> =0V
Reverse transfer capacitance	Crss	_	60	_	рF	f=1MHz
Turn-on delay time	td(on)	_	5	_	ns	Io=2.5A, Voo≒50V
Rise time	tr	-	20	_	ns	V <sub>GS</sub> =10V
Turn-off delay time	td(off)	_	50	_	ns	RL=20Ω
Fall time	tr	_	20		ns	R <sub>G</sub> =10Ω

<sup>\*</sup> Pw≦300 μs, Duty cycle≦1%

# ●Electrical characteristic curves

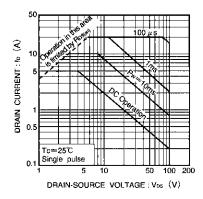


Fig.1 Maximum Safe Operating Area

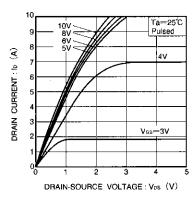


Fig.2 Typical Output Characteristics

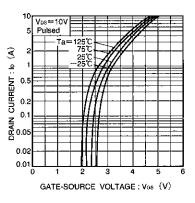


Fig.3 Typical Transfer Characteristics

# Electrical characteristic curves

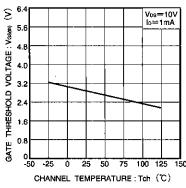


Fig.4 Gate Threshold Voltage vs. Channel Temperature

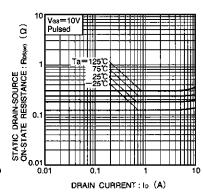


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current ( I )

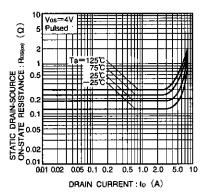


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current ( II )

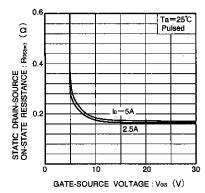


Fig.7 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

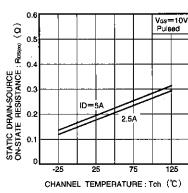


Fig.8 Static Drain-Source On-State Resistance vs. Channel Temperature

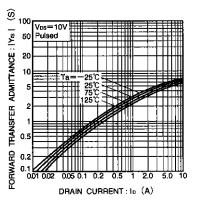


Fig.9 Forward Transfer Admittance vs. Drain Current

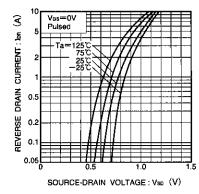


Fig.10 Reverse Drain Current vs. Source-Drain Voltage ( I )

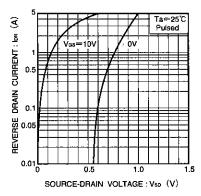


Fig.11 Reverse Drain Current vs. Source-Drain Voltage (II)

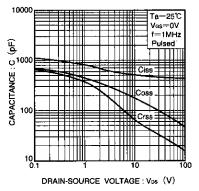


Fig.12 Typical Capacitance vs. Drain-Source Voltage

# Electrical characteristic curves

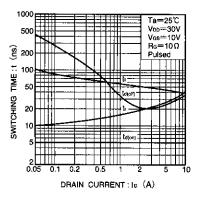


Fig.13 Switching Characteristics (See Figure. 16 and 17 for measurement circuits)

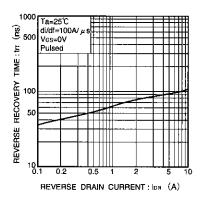


Fig.14 Reverse Recovery Time vs. Reverse Drain Current

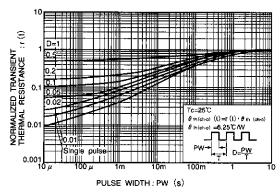


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width

# Switching characteristics measurement circuit

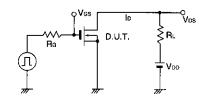


Fig.16 Switching Time Measurement Circuit

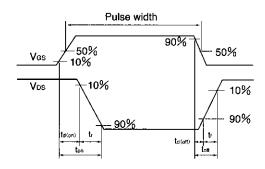


Fig.17 Switching Time Waveforms

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